WELLCOMP TECHNOLOGY CO., LTD

APPROVAL SHEET

Model Name	Metal Strip Current Sensing Resistor
Part Number	WMCSE0603R010FATx
Customer Name	
Customer P/N	
Issued Date	

Customer			Maker		
Approved	Checked	Inspector	Checked	Prepared	



元璽科技股份有限公司

WELLCOMP TECHNOLOGY CO., LTD.

桃園縣龜山鄉南上路 526 號

NO. 526, NangShang RD., Guishan Township

Taoyuan Country 333, Taiwan Tel: +886-3-2220730, 2220731

Fax: +886-3-2222820



Metal Strip Current Sensing Resistor

Document No: 20120803001 Issued Date: 2012/08/03

Version: A01

Features

- ◆Able to withstand high temperature and high current
- ◆Ultra Low sensing resistance
- ◆Excellent frequency response
- ♦Chip size: 0805
- Lead free, RoHS compliant for global applications and halogen free

Application

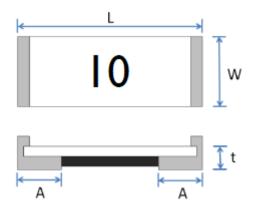
- ◆Mobile electronic equipment-Cellular phone, NB Tablet PC, GPS, DSC, HDD
- ◆DC-DC converter, Adapter, Battery pack and charger
- ◆Switching power supply
- ◆Voltage Regulation module
- ◆Power management applications

Part Numbering System

WMCSE 0603 R010 F A T A

- (1) (2) (3) (4) (5) (6) (7)
- (1) Series Code
- (2) Size (EIA): Length x Width
- (3) Resistance: R002=2m Ω , R009=9m Ω
- (4) Tolerance: F=+/-1%, G=+/-2%, J=+/-5%
- (5) Power Rating: A=1/4W S=1/2W, C=1W, D=1.5W, E=2W
- (6) Packaging: T- Embossed paper tape, 7" reel E-Embossed plastic tape, 7" reel
- (7) Factory Code, A=Taiwan Factory

Dimension



Туре	Dimensions(mm) L W t A					
(inch size)						
WMCSE0603	1.60±0.10	0.80±0.1	0.55±0.15	0.30±0.20		



Metal Strip Current Sensing Resistor

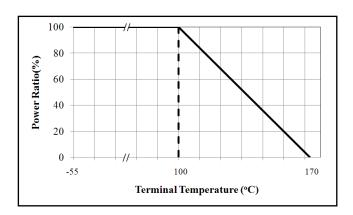
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Electrical Specification

Item	Power Rating	Resistance Range(m Ω)	Operation Temp. Range	TCR (PPM/°C)
MCSE0603	1/4W	10	-55~+170°C	±75

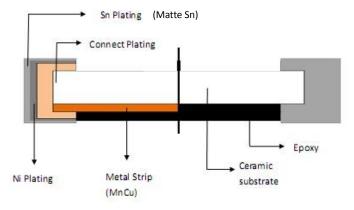
Derating Curve



Construction



Top view



Side view



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Performances

Environmental Performance

No.	Item	Test Condition	Specification
1	Short Time Overload	Voltage equal to 5 time rated power for 5 sec , (JIS-C5202-5.5)	Δ R: ±(1%+0.0005Ω)
2	Temperature Coefficient of Resistance (T.C.R.)	+25°C/+125°C. (JIS-C5202-5.2) $TCR \text{ (ppm/°C)} = \frac{\Delta R}{R \times \Delta t} \times 10^{6}$	Refer to Electrical Specification
3	Damp Heat with Load	The specimens shall be placed in a chamber and subjected to a relative humidity of 90~95% percent and a temperature of 40° ±2°C for the period of 1000 hrs. (MIL-STD-202, Method 103)	Δ R: ±(1%+0.0005Ω)
4	High Temperature Exposure	The ship (mounted on board) is exposed in the heat chamber 125 $\pm 3^{\circ}$ C for 1000 hrs. (JIS-C5202-7.2)	Δ R: ±(1%+0.0005Ω)
5	Load Life	Apply rated power at 70±2°C for 1000 hours with 1.5 hours ON and 0.5 hour OFF. (JIS-C5202-7.10)	ΔR: ±(1%+0.0005Ω)
6	Rapid change of temperature	The chip (mounted on board) is exposed, -55±3°C (30min.)/+125±2°C (30min.) for 5 cycles. The following conditions as the following figure. (JIS-C5202-7.4) Ambient temperature	ΔR: ±(1%+0.0005Ω)



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Function Performance

No.	ltem	Test Condition	Specification
1	Bending Strength	Mount the chip to test substrate. Apply pressure in direction of arrow unit band width reaches 2mm(+0.2/-0mm) illustrated in the figure below and hold for 10±1 sec. (JIS-C5202-6.1) Unit: mm Position before bend Testing printed circuit board	ΔR: ±(1%+0.0005Ω)
5	Solvent Resistance	The chip is completed immersion of the specimens in the isopropyl alcohol for 3 *+5, -0) min., 25°C ±5°C. ((MIL-STD-202, Method 215)	Verify marking permanency. (Nor required for laser etched parts or parts with no marking)
6	Resistance to solder Heat	The specimen chip shall be immersed into the flux specified in the solder bath $260\pm5^{\circ}$ C for 10 ± 1 sec. (MIL-STD-202, Method 210)	Δ R: ±(1%+0.0005Ω)
7	Solderability	The specimen chip shall be immersed into the flux specified in the solder bath $235\pm5^{\circ}\mathbb{C}$ for 2 ± 0.5 sec. It shall be immersed to a point 10mm from its root. (Sn96.5/Ag3.0/Cu0.5) (JIS-C5 202-6.11) Moiten solder Specimen SNID $h = 10 \text{ mm}$ $H = 10 \text{ mm}$ min.	Solder shall be covered 95% or more of the electrode area.

Remark:

- a. 0.5 W with total solder pad trace size of 100 mm².
- b. 1.0 W with total solder pad trace size of 100 mm².
- c. 1.5 W with total solder pad trace size of 200 mm².
- d. 2.0 W with total solder pad trace size of 300 mm².



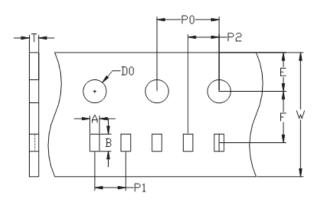
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Tape Packaging Specifications

◆Paper Tape Specifications



Unit:mm

Туре	Carrier Dimensions									
Туре	Α	В	E	F	W	P0	P1	P2	D0	Т
0805	1.1±0.1	1.9±0.1	1.75±0.1	3.5±0.05	8.0±0.2	4.0±0.1	4.0±0.1	2.0±0.05	1.55±0.05	0.70±0.1

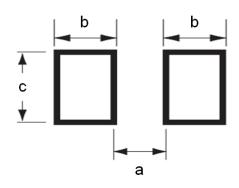
Packaging

Size EIA (EIAJ)	0603
Standard Packing Quantity (pcs /reel)	5,000

Storage Conditions

Temperature : $5^{\circ}35^{\circ}C$, Humidity : $40^{\circ}75\%$

Recommended Solder Pad Layout



Typo	Pad Layout Dimension (mm)				
Type	a	b	C		
0603	0.90	0.70	1.00		



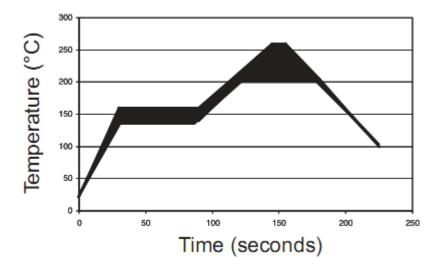
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Soldering Recommendations

- ◆ Peak reflow temperatures and durations:
 - IR Reflow Peak = 260°C max for 10 sec
 - Wave Solder = 260° C max for 10 sec
 - IR reflow or wave solder can be proceed for 3 times
- ◆ Soldering Iron: Temperature 350°C, dwell time shall be less than 3 sec.
- ◆ Compatible with lead and lead-free solder reflow processes
- ◆ Recommended IR Reflow Profile:



ECN

Engineering Change Notice: The customer will be informed with ECN if there is significant modification on the characteristics and materials described in Approval Sheet.